

Monolithic Amplifier PMA2-123LN+

 50Ω 0.5 to 12 GHz

THE BIG DEAL

- Ultra wideband, 0.5 to 12 GHz
- Flat gain over wideband, 17.6 dB with ±2.0 dB
- Low noise figure, 2.6 dB at 8 GHz
- · High IP3, up to +28 dBm



Generic photo used for illustration purposes only

CASE STYLE: MC1631-1

+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

APPLICATIONS

- WiFi
- WLAN
- UMTS
- LTE
- WiMAX
- S-band Radar
- C-band Satcom

PRODUCT OVERVIEW

The PMA2-123LN+ is a PHEMT based wideband, low noise MMIC amplifier with a unique combination of low noise, high IP3, and flat gain over wideband making it ideal for sensitive, high-dynamic-range receiver applications. This design operates on a single 5V or 6V supply, is well matched for 50Ω and comes in a tiny, low profile package (2 x 2 mm, 8 lead MCLP), accommodating dense circuit board layouts.

KEY FEATURES

Feature	Advantages		
Low noise • 2.2 dB at 2 GHz • 2.6 dB at 8 GHz	Enables lower system noise figure performance.		
High IP3 • +28 dBm at 2 GHz • +27 dBm at 8 GHz	Combination of low noise and high IP3 makes this MMIC amplifier ideal for use in low noise receiver front end (RFE) as it gives the user advantages of sensitivity and two-tone IM performance at both ends of the dynamic range.		
Low operating voltage, 5V/6V.	Achieves high IP3 using low voltage.		
2 x 2mm 8-lead MCLP package	Tiny footprint saves space in dense layouts while providing low inductance, repeatable transitions, and excellent thermal contact to the PCB.		
Wide bandwidth with flat gain ±0.3 dB over 0.5 to 2 GHz ±0.7 dB over 0.5 to 6 GHz ±1.2 dB over 0.5 to 8 GHz ±2.0 dB over 0.5 to 12 GHz	Enables usage in wideband applications flatttering networks.		

REV. B ECO-011027 PMA2-123LN+ RS/CP 211209





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ELECTRICAL SPECIFICATIONS¹ AT 25°C, UNLESS NOTED OTHERWISE

Parameter	Condition		V _{DD} =6.0		V _{DD} =5.0			
	(GHz)	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		0.5		12.0	0.5		12.0	GHz
	0.5		2.5			2.5		
	2.0		2.2			2.1		
Noise Figure	8.0		2.6			2.5		dB
	10.0		3.0			2.9		
	12.0		3.1			3.0		
	0.5		18.6			17.7		
	2.0		19.2			18.3		
Gain	8.0	15.2	16.8	18.5	14.5	16.1	17.8	dB
	10.0		16.1			15.4		
	12.0		15.3			14.7		
	0.5		7.0			6.2		
	2.0		12.0			10.5		
Input Return Loss	8.0		9.8			9.1		dB
	10.0		9.7			9.1		
	12.0		9.8			9.6		
	0.5		11.4			9.6		
	2.0		14.5			12.4		
Output Return Loss	8.0		22.0			19.4		dB
	10.0		16.5			15.9		
	12.0		9.6			8.9		
	0.5		15.2			13.9		
	2.0		15.3			13.9		
Output Power at 1dB Compression ²	8.0		14.9			13.3		dBm
	10.0		14.9			13.3		
	12.0		14.0			12.5		
	0.5		27.4			24.9		
	2.0		28.0			25.1		
Output IP3	8.0		27.0			24.6		dBm
	10.0		26.8			24.8		
	12.0		26.3			24.8		
Device Operating Voltage (V _{DD})			6.0			5.0		V
Device Operating Current (I _{DD})			68	82		51		mA
Device Current Variation vs. Temperature ³			-11.7			9.3		μΑ/°C
Device Current Variation vs. Voltage			0.0187			0.0184		mA/mV
Thermal Resistance, junction-to-ground lead	ITD MD014 C		107			107		°C/W

^{1.} Measured on Mini-Circuits Characterization Test Board TB-MB014. See Characterization Test Circuit (Fig. 1)

MAXIMUM RATINGS⁴

Parameter	Ratings
Operating Temperature (ground lead)	-40°C to 85°C
Storage Temperature	-65°C to 150°C
Junction Temperature	160
Total Power Dissipation	0.7W
Input Power (CW), Vd=5,6V ⁵	+20 dBm (0.7 - 7.75 GHz) 5 minutes max. +22 dBm (7.75 - 15 GHz) 5 minutes max. +8 dBm (continuous)
DC Voltage	7V

^{4.} Permanent damage may occur if any of these limits are exceeded. Electrical maximum ratings are not intended for continuous normal operation.



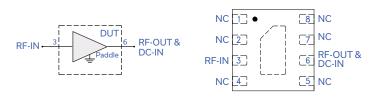
^{2.} Current increases at P1dB up to 10mA typ. at 5Volts VDD 3. (Current at 85° C - Current at -45° C)/130

^{5.} Measured on Mini-Circuits Test Board, TB-MB014



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SIMPLIFIED SCHEMATIC & PAD DESCRIPTION



Function	Pad Number	Description (See Figure 2)
RF-IN	3	Connects to RF input via C1
RF-OUT & DC-IN	6	Connects to RF out and $V_{\rm DD}$ via Bias-Tee
Ground	Paddle	Connects to ground
No Connection	1,2,4,5,7,8	Not used internally. Connected to ground on Test Board

CHARACTERIZATION TEST CIRCUIT

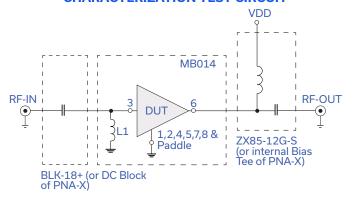


Fig 1. Application and Characterization Circuit

Note: This block diagram is used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-MB014+)

Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

- 1. Gain and Return loss: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.

RECOMMENDED APPLICATION CIRCUIT

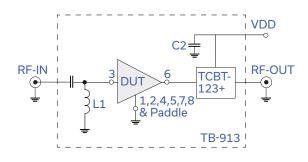
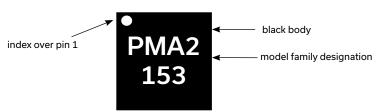


Fig 2. Test board (TB-913+) includes case, connectors and components soldered to PCB. (TB-913+ is a 3-layer PCB. See TB-913+ drawing.)

Component	Size	Value
L1	0402	20 nH
C1	0402	0.1 µF
C2	0603	0.01 μF

PRODUCT MARKING



Marking may contain other features or characters for internal lot control





Monolithic Amplifier PMA2-123LN+

ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD. TO ACCESS

CLICK HERE

	Data Table	
Performance Data	Swept Graphs	
	S-Parameter (S2P Files) Data Set (.zip file)	
Case Style	MC1631-1 Plastic package, exposed paddle, lead finish: tin silver over nickel	
Tape & Reel	F66	
Standard quantities available on reel	7" reels with 20, 50, 100, 200, 500,1K or 2K devices	
Suggested Layout for PCB Design	PL-490	
Evaluation Board	TB-913+	
Environmental Ratings	ENV08T1	

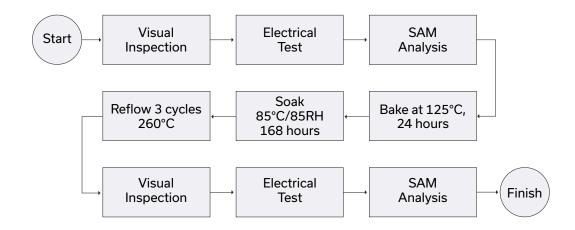
ESD RATING

Human Body Model (HBM): Class 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

MSL TEST FLOW CHART



NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
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